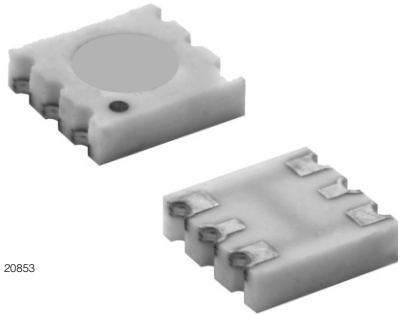


Power SMD LED CLCC-6 Warm White Flat



FEATURES

- Utilizing InGaN technology
- Very low thermal resistance, high optical power
- Optical efficiency 24 lm/W
- Luminous intensity and color grouping
- Luminous intensity ratio per package unit $I_{Vmax}/I_{Vmin} \leq 1.6$
- ESD-withstand voltage: up to 1 kV according to JESD22-A114-B
- Compatible with IR reflow solder processes according to CECC 00802 and J-STD-020C
- Lead (Pb)-free device
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- Preconditioning: acc. to JEDEC level 4
- Automotive qualified AEC-Q101
- Very flat package (0.9 mm)



DESCRIPTION

The VLMW621. is one of the most robust and light efficient LEDs in the market. The small size and wide viewing angle make these LEDs a prime choice for backlighting applications and front panel indicators, especially where space is at a premium. Its ceramic package makes it the ideal light source in applications of high thermal considerations allowing the additional current drive for a maximum light output while maintaining a high service life of up to 50K h. The reflector inside this package is filled with a mixture of silicone and TAG phosphor. The TAG phosphor converts the blue emission partially to yellow, which mixes with the remaining blue to white.

APPLICATIONS

- Camera flash light
- Interior and exterior automotive lighting: brake lights, backlighting, side markers
- Indicator lighting
- Signal and symbol luminaire
- Marker lights
- Dashboard illumination

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD CLCC-6 flat
- Product series: power
- Angle of half intensity: $\pm 60^\circ$

PARTS TABLE			
PART	COLOR, LUMINOUS INTENSITY (at $I_F = 140$ mA)	LUMINOUS FLUX (TYP.)	TECHNOLOGY
VLMW621BADAK3L5-08	Warm white, $I_V = (1800 \text{ to } 5600)$ mcd	10 lm	InGaN/TAG
VLMW621BADAK3L5-18	Warm white, $I_V = (1800 \text{ to } 5600)$ mcd	10 lm	InGaN/TAG
VLMW621CADBK3L5-08	Warm white, $I_V = (2800 \text{ to } 7100)$ mcd	13 lm	InGaN/TAG
VLMW621CADBK3L5-18	Warm white, $I_V = (2800 \text{ to } 7100)$ mcd	13 lm	InGaN/TAG



ABSOLUTE MAXIMUM RATINGS ¹⁾ VLMW621.				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Forward current		I_F	150	mA
Power dissipation		P_{tot}	650	mW
Junction temperature		T_j	+ 125	°C
Surge current $T_j < 400$ ms, $d = 0.3$, $T_j < 65$ °C			350	mA
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Thermal resistance junction/pin	Metal core pcb 960 mm ² per LED	R_{thJP}	40	K/W
Thermal resistance junction/ambient		R_{thJA}	90	K/W

Note:

Not designed for reverse operation

¹⁾ $T_{amb} = 25$ °C, unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS ¹⁾ VLMW621., WARM WHITE							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
Luminous intensity	$I_F = 140$ mA	VLMW621BADA	I_V	1800		5600	mcd
		VLMW621CADB	I_V	2800		7100	mcd
Luminous flux <i>calculated</i> ³⁾	$I_F = 140$ mA	VLMW621BADA	ϕ_V	5400		16 800	mlm
		VLMW621CADB	ϕ_V	8400		22 300	mlm
Chromaticity coordinate x acc. to CIE 1931	$I_F = 140$ mA		x		0.40		
Chromaticity coordinate y acc. to CIE 1931	$I_F = 140$ mA		y		0.39		
Angle of half intensity	$I_F = 140$ mA		φ		± 60		deg
Forward voltage ²⁾	$I_F = 140$ mA		V_F	2.9	3.3	4.3	V
Temperature coefficient of V_F	$I_F = 140$ mA		TC_{VF}		- 3		mV/K
Temperature coefficient of I_V	$I_F = 140$ mA		TC_{IV}		- 0.4		%/K

Note:

Not designed for reverse operation

¹⁾ $T_{amb} = 25$ °C, unless otherwise specified

²⁾ Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of ± 0.05 V

³⁾ Theoretical correlation for 120° emission angle

LUMINOUS INTENSITY/FLUX CLASSIFICATION WARM WHITE		
GROUP	LUMINOUS INTENSITY I_V (mcd)	
	MIN.	MAX.
STANDARD		
BA	1800	2240
BB	2240	2800
CA	2800	3550
CB	3550	4500
DA	4500	5600
DB	5600	7100
EA	7100	9000

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, each single wavelength group is packed in a single reel.

In order to ensure availability, single wavelength groups can not be ordered.

CHROMATICITY COORDINATED GROUPS FOR WARM WHITE SMD LED		
	X	Y
K3	0.373	0.350
	0.387	0.358
	0.393	0.376
	0.378	0.368
K4	0.378	0.368
	0.393	0.376
	0.399	0.395
	0.383	0.386
K5	0.383	0.386
	0.399	0.395
	0.405	0.412
	0.388	0.403
L3	0.387	0.358
	0.400	0.366
	0.407	0.384
	0.393	0.376
L4	0.393	0.376
	0.407	0.384
	0.414	0.402
	0.399	0.395
L5	0.399	0.395
	0.414	0.402
	0.421	0.420
	0.405	0.412

Note:

Chromaticity coordinate groups are tested at a current pulse duration of 25 ms and a tolerance of ± 0.01 .

TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

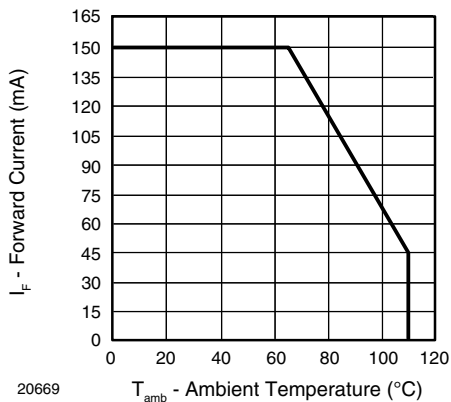


Figure 1. Forward Current vs. Ambient Temperature

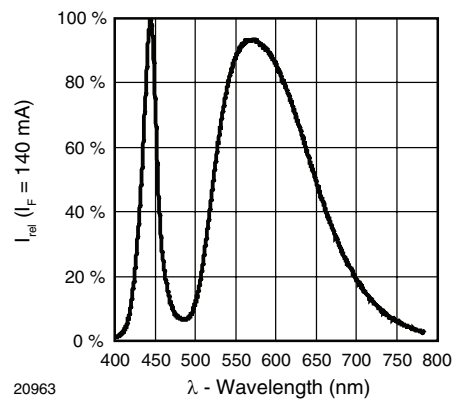


Figure 2. Relative Spectral Emission

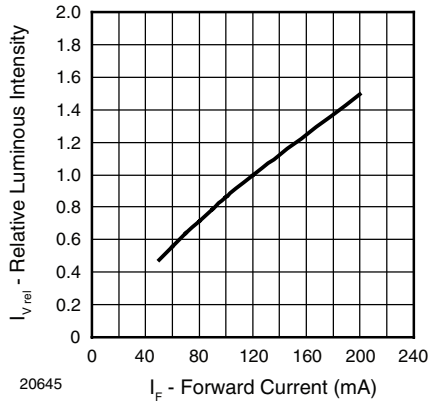


Figure 3. Relative Luminous Intensity vs. Forward Current

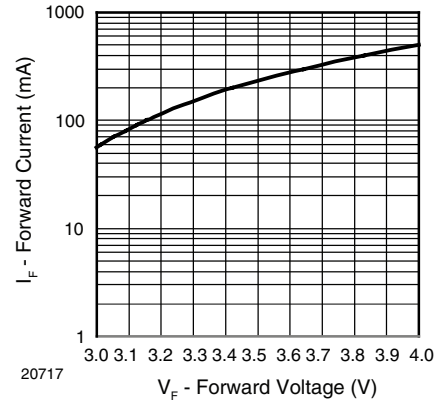


Figure 6. Forward Current vs. Forward Voltage

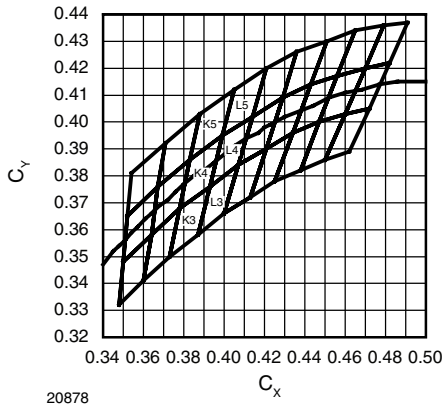


Figure 4. Coordinates of Color Groups

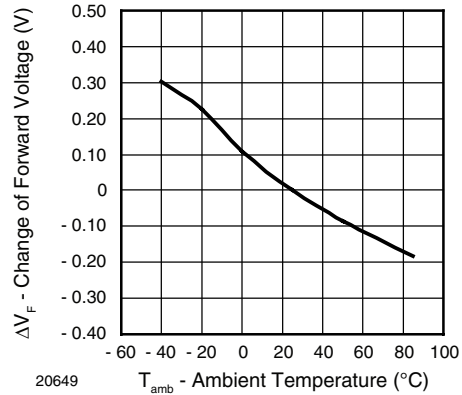


Figure 7. Forward Voltage vs. Ambient Temperature

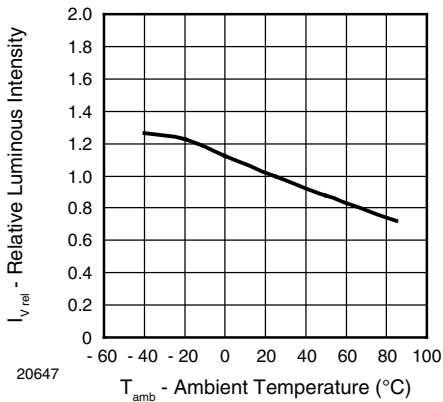


Figure 5. Relative Luminous Flux vs. Ambient Temperature

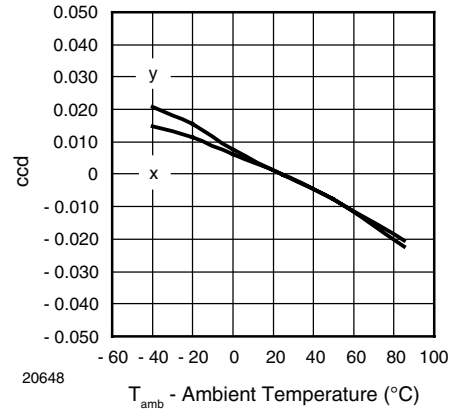


Figure 8. Color Coordinate vs. Ambient Temperature

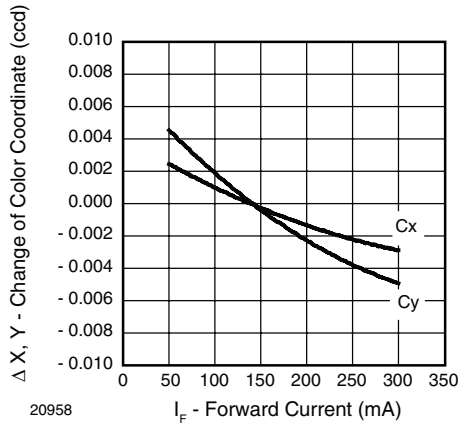
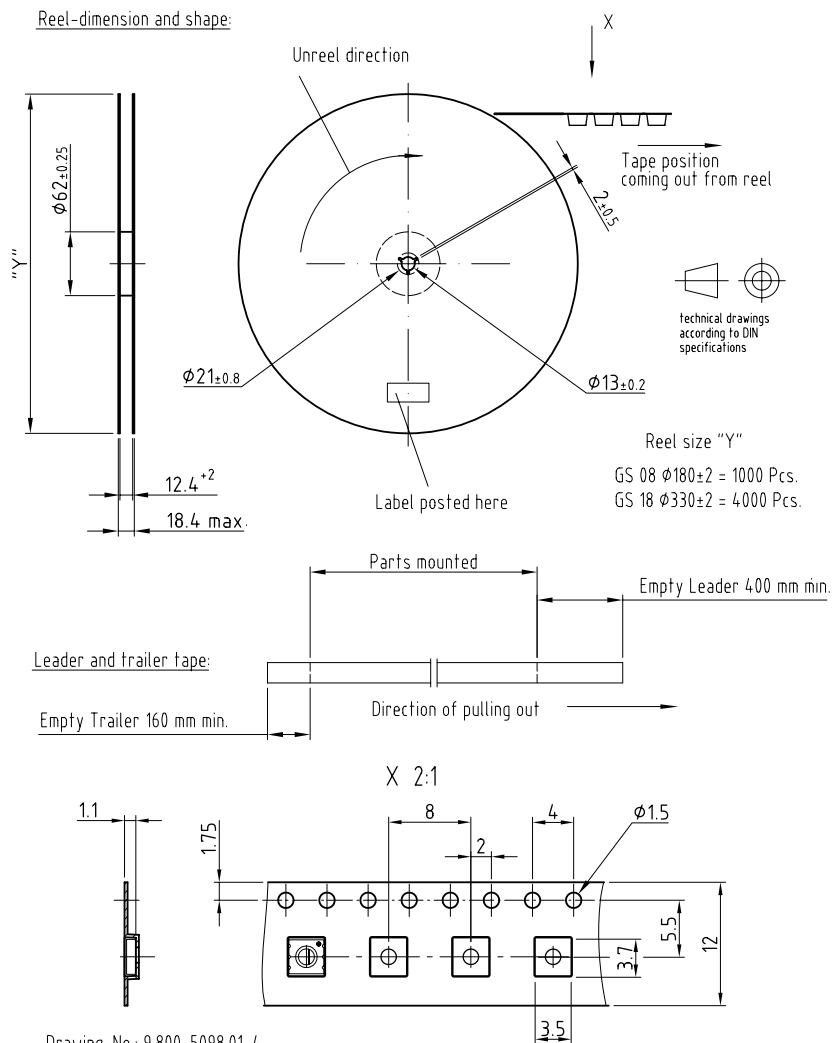


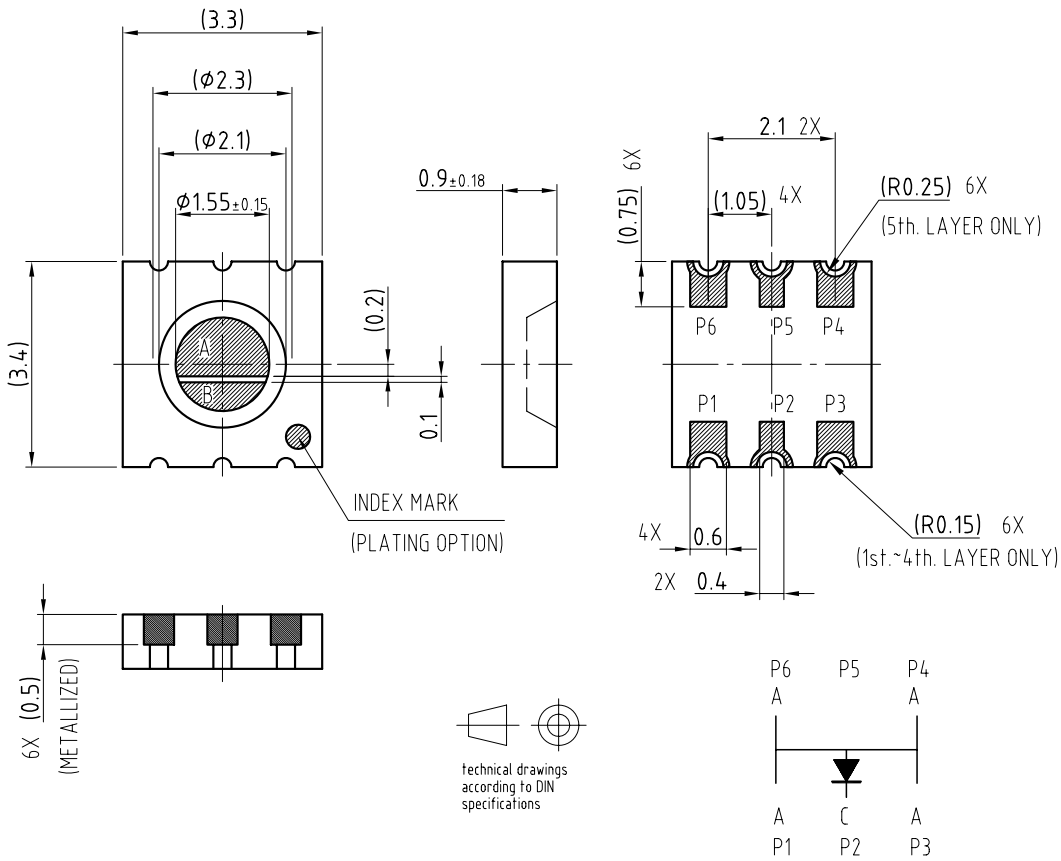
Figure 9. X, Y Coordinate vs. Forward Current

TAPING DIMENSIONS in millimeters



Drawing-No.: 9.800-5098.01-4
Issue: 1; 17.09.07
20869

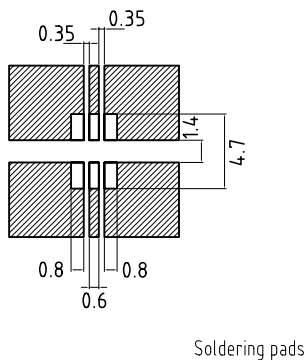
PACKAGE DIMENSIONS in millimeters



Drawing-No.: 6.581-5009.01-4
 Issue: 1; 21.08.07
 20833

Not indicated tolerances ±0.2

SOLDERING PADS DIMENSIONS in millimeters



Drawing-No.: 6.581-5006.01-4
 Issue: 1; 07.02.07
 20598

SOLDERING PROFILE

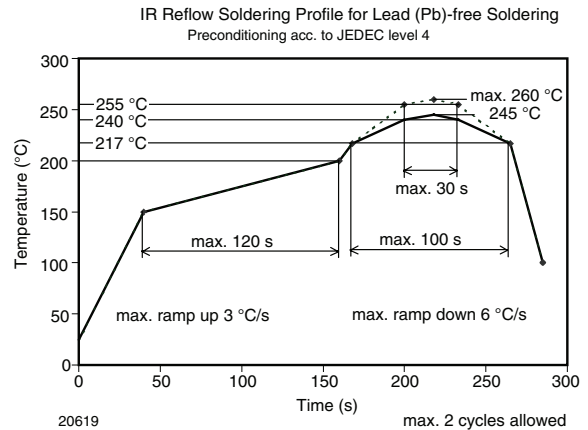
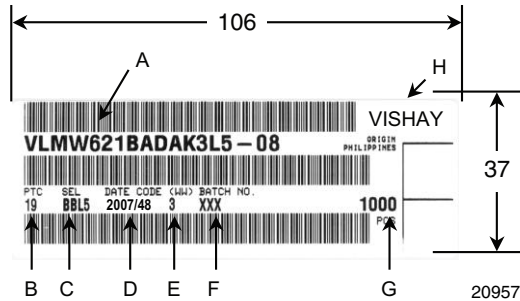


Figure 10. Vishay Lead (Pb)-free Reflow Soldering Profile (acc. to J-STD-020C)

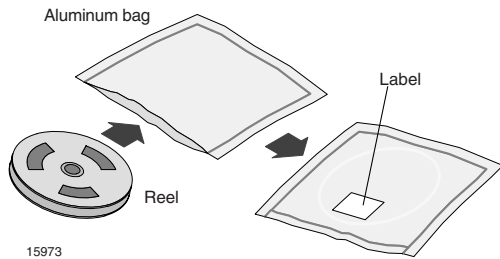
**BAR CODE PRODUCT LABEL
EXAMPLE:**



- A) Type of component
- B) Manufacturing plant
- C) SEL - selection code (bin):
e.g.: BB = code for luminous intensity group
L5 = code for chromaticity coordinate
- D) Date code year/week
- E) Day code (e.g. 3: Wednesday)
- F) Batch no.
- G) Total quantity
- H) Company code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminum bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

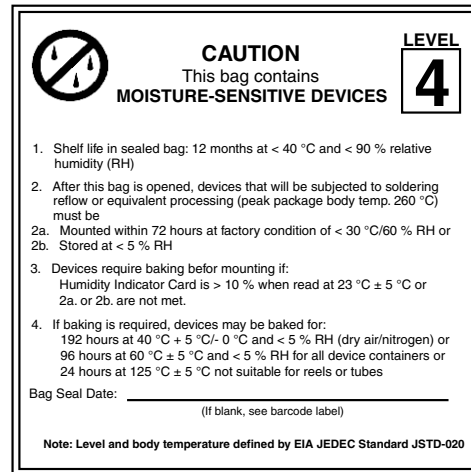
- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 72 h under these conditions moisture content will be too high for reflow soldering.

In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

- 192 h at 40 °C + 5 °C/- 0 °C and < 5 % RH (dry air/nitrogen) or
- 96 h at 60 °C + 5 °C and < 5 % RH for all device containers or
- 24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 4 label is included on all aluminum dry bags.



Example of JESD22-A112 level 4 label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

**VISHAY SEMICONDUCTORS STANDARD
BAR CODE LABELS**

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA.
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

The IEC/EN standards require that the desired classification Accessible Emission Limit shall not be exceeded in "Normal" and "Single Fault Conditions". This product is in Compliance with the requirement in CEN/IEC/EN60825-1 to ensure that required classifications are not exceeded in single fault conditions.

We reserve the right to make changes to improve technical design
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



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